NSN 5961-01-011-4957

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Inclosure Material: Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** Between 0.500 inches and 0.750 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Internal Configuration:** Field effect Electrode Internally-electrically Connected To Case: Gate **Mounting Method:** Terminal **Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 drain to gate voltage and 35.0 drain to source voltage and -35.0 gate to source voltage **Current Rating Per Characteristic:** 10.00 milliamperes gate current **Power Rating Per Characteristic:** 300.0 milliwatts total power dissipation Maximum Operating Tempurature Per Measurement Point: 200.0 degrees celsius junction **Test Data Document:** 81349-mil-c-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:**

81349-mil-s-19500/428 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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